



DDA (LO-R1) H

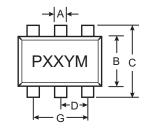
PNP PRE-BIASED SMALL SIGNAL SOT-563 DUAL SURFACE MOUNT TRANSISTOR

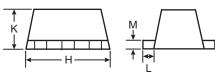
Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- Built-In Biasing Resistors
- Lead Free By Design/RoHS Compliant (Note 3)

Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.005 grams (approx.)



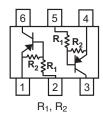


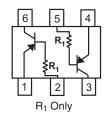
SEE NOTE 1

	SOT-563										
Dim	Min	Max	Тур								
Α	0.15	0.30	0.25								
В	1.10	1.25	1.20								
С	1.55	1.55 1.70 1.60									
D		0.50									
G	0.90	1.10	1.00								
Н	1.50	1.70	1.60								
K	0.56	0.60	0.60								
L	0.15	0.25	0.20								
М	0.10	0.18	0.11								
All	Dimens	ions in	mm								

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P/N	R1 (NOM)	R2 (NOM)	MARKING
DDA122LH	0.22KΩ	10KΩ	P81
DDA142JH	0.47KΩ	10KΩ	P82
DDA122TH	0.22KΩ	OPEN	P83
DDA142TH	0.47KΩ	OPEN	P84





SCHEMATIC DIAGRAM, TOP VIEW

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage (6) to (1) and (3) to (4)	Vcc	-50	V	
Input Voltage (2) to (1) and (5) to (4) DDA122LH DDA142JH		V _{IN}	+5 to -6 +5 to -6	V
Input Voltage (1) to (2) and (4) to (5) DDA122TH DDA142TH		V _{EBO (MAX)}	-5	V
Output Current All		Ic	-100	mA
Power Dissipation	Pd	150	mW	
Thermal Resistance, Junction to Ambient	R ₀ JA	833	°C/W	
Operating and Storage and Temperature F	Range	T _j , T _{STG}	-55 to +150	°C

- Notes: 1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).
 - 2. Mounted on FR4 Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
 - 3. No purposefully added lead.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

R1, R2 Types

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	DDA122LH DDA142JH	V _{I(off)}	-0.3 -0.3	_	_	٧	$V_{CC} = -5V$, $I_{O} = -100\mu A$
F	DDA122LH DDA142JH	V _{I(on)}	_	_	-2.0 -2.0	٧	V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA
Output Voltage		V _{O(on)}	_	_	-0.3V	V	$I_0/I_1 = -5$ mA/-0.25mA
Input Current DDA122LH DDA142JH		II	_	_	-28 -13	mA	V _I = -5V
Output Current	,		_	_	-0.5	μА	V _{CC} = -50V, V _I = 0V
DC Current Gain DDA122LH DDA142JH		G _l	56 56	_	_	_	V _O = -5V, I _O = -10mA
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

^{*} Transistor - For Reference Only

Electrical Characteristics @ T_A = 25°C unless otherwise specified

R1-Only Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltag	BV _{CBO}	-50	_	_	V	$I_C = -50\mu A$	
Collector-Emitter Breakdown Volta	age	BV _{CEO}	-40	_	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	_	_	V	I _E = -50μA I _E = -50μA	
Collector Cutoff Current	Collector Cutoff Current		_	_	-0.5	μΑ	V _{CB} = -50V
Emitter Cutoff Current DDA122TH DDA142TH		I _{EBO}	_	_	-0.5 -0.5	μА	V _{EB} = -4V
Collector-Emitter Saturation Voltage	ge	V _{CE(sat)}	_	_	-0.3	V	$I_C = -5mA$, $I_B = -0.25mA$
DC Current Transfer Ratio DDA122TH DDA142TH		h _{FE}	100 100	250 250	600 600	_	$I_C = -1 \text{mA}, V_{CE} = -5 \text{V}$
Gain-Bandwidth Product*		f _T	_	200	_	MHz	$V_{CE} = -10V$, $I_E = 5mA$, $f = 100MHz$

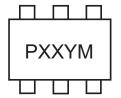
^{*} Transistor - For Reference Only

Ordering Information (Note 4)

Device	Packaging	Shipping
DDA122LH-7	SOT-563	3000/Tape & Reel
DDA142JH-7	SOT-563	3000/Tape & Reel
DDA122TH-7	SOT-563	3000/Tape & Reel
DDA142TH-7	SOT-563	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



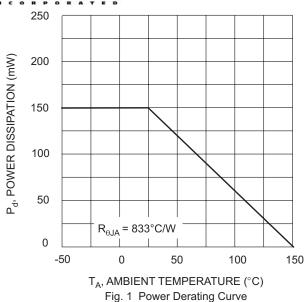
XXX = Product Type Marking Code (See Page 1)

YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	20	02	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code		N	Р	R	S	T	U	V	W	X	Y	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





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